



# PJU4NA90 / PJD4NA90 / PJP4NA90 / PJF4NA90

## 900V N-Channel MOSFET

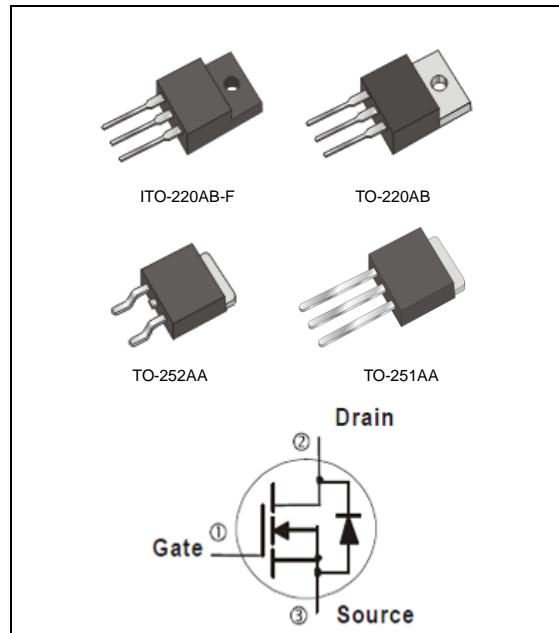
|                |              |                |            |
|----------------|--------------|----------------|------------|
| <b>Voltage</b> | <b>900 V</b> | <b>Current</b> | <b>4 A</b> |
|----------------|--------------|----------------|------------|

### Features

- $R_{DS(ON)}, V_{GS}@10V, I_D@2A < 3.4\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std.  
(Halogen Free)

### Mechanical Data

- Case: TO-251AA, TO-252AA, TO-220AB, ITO-220AB-F Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- TO-251AA Approx. Weight : 0.0104 ounces, 0.297grams
- TO-252AA Approx. Weight : 0.0104 ounces, 0.297grams
- TO-220AB Approx. Weight : 0.065 ounces, 1.859 grams
- ITO-220AB-F Approx. Weight : 0.068 ounces, 1.945 grams



### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

| PARAMETER   |                                 | SYMBOL          | TO-251AA | TO-220AB | ITO-220AB-F | TO-252AA | UNITS                     |
|---|---------------------------------|-----------------|----------|----------|-------------|----------|---------------------------|
| Drain-Source Voltage                              |                                 | $V_{DS}$        | 900      |          |             |          | V                         |
| Gate-Source Voltage                               |                                 | $V_{GS}$        | $\pm 30$ |          |             |          | V                         |
| Continuous Drain Current                          |                                 | $I_D$           | 4        |          |             |          | A                         |
| Pulsed Drain Current                              |                                 | $I_{DM}$        | 16       |          |             |          | A                         |
| Single Pulse Avalanche Energy <sup>(Note 1)</sup> |                                 | $E_{AS}$        | 344      |          |             |          | mJ                        |
| Power Dissipation                                 | $T_C=25^\circ\text{C}$          | $P_D$           | 90       | 140      | 44          | 90       | W                         |
|   | Derate above $25^\circ\text{C}$ |                 | 0.72     | 1.12     | 0.35        | 0.72     | W/ $^\circ\text{C}$       |
| Operating Junction and Storage Temperature Range  |                                 | $T_J, T_{STG}$  | -55~150  |          |             |          | $^\circ\text{C}$          |
| Typical Thermal resistance                        |                                 |                 |          |          |             |          |                           |
| - Junction to Case                                |                                 | $R_{\theta JC}$ | 1.39     | 0.89     | 2.84        | 1.39     | $^\circ\text{C}/\text{W}$ |
| - Junction to Ambient                             |                                 | $R_{\theta JA}$ | 110      | 62.5     | 120         | 110      |                           |

- Limited only By Maximum Junction Temperature



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### Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

| PARAMETER   | SYMBOL       | TEST CONDITION                                      | MIN. | TYP.     | MAX.      | UNITS    |
|---|--------------|---|------|----------|-----------|----------|
| <b>Static</b>   |              |   |      |          |           |          |
| Drain-Source Breakdown Voltage                        | $BV_{DSS}$   | $V_{GS}=0V, I_D=250\mu A$                           | 900  | -        | -         | V        |
| Gate Threshold Voltage                                | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=250\mu A$                       | 2    | -        | 4         | V        |
| Drain-Source On-State Resistance                      | $R_{DS(on)}$ | $V_{GS}=10V, I_D=2A$                                | -    | 2.7      | 3.4       | $\Omega$ |
| Zero Gate Voltage Drain Current                       | $I_{DSS}$    | $V_{DS}=900V, V_{GS}=0V$                            | -    | 0.03     | 1.0       | $\mu A$  |
| Gate-Source Leakage Current                           | $I_{GSS}$    | $V_{GS}=\pm 30V, V_{DS}=0V$                         | -    | $\pm 10$ | $\pm 100$ | nA       |
| Diode Forward Voltage                                 | $V_{SD}$     | $I_S=4A, V_{GS}=0V$                                 | -    | -        | 1.4       | V        |
| <b>Dynamic</b> (Note 4)                               |              |   |      |          |           |          |
| Total Gate Charge                                     | $Q_g$        | $V_{DS}=720V, I_D=4A,$<br>$V_{GS}=10V$ (Note 2,3)   | -    | 17       | -         | nC       |
| Gate-Source Charge                                    | $Q_{gs}$     |   | -    | 4.1      | -         |          |
| Gate-Drain Charge                                     | $Q_{gd}$     |   | -    | 7.6      | -         |          |
| Input Capacitance                                     | $C_{iss}$    | $V_{DS}=25V, V_{GS}=0V,$<br>$f=1.0\text{MHz}$       | -    | 710      | -         | pF       |
| Output Capacitance                                    | $C_{oss}$    |   | -    | 82       | -         |          |
| Reverse Transfer Capacitance                          | $C_{rss}$    |   | -    | 5        | -         |          |
| Turn-On Delay Time                                    | $t_{d(on)}$  | $V_{DD}=450V, I_D=4A,$<br>$R_G=25\Omega$ (Note 2,3) | -    | 15       | -         | ns       |
| Turn-On Rise Time                                     | $t_r$        |   | -    | 27       | -         |          |
| Turn-Off Delay Time                                   | $t_{d(off)}$ |   | -    | 40       | -         |          |
| Turn-Off Fall Time                                    | $t_f$        |   | -    | 29       | -         |          |
| <b>Drain-Source Diode</b>                             |              |   |      |          |           |          |
| Maximum Continuous Drain-Source Diode Forward Current | $I_S$        | ---   | -    | -        | 4         | A        |
| Maximum Pulsed Drain-Source Diode Forward Current     | $I_{SM}$     | ---   | -    | -        | 16        | A        |
| Reverse Recovery Time                                 | $t_{rr}$     | $V_{GS}=0V, I_S=4A$                                 | -    | 540      | -         | ns       |
| Reverse Recovery Charge                               | $Q_{rr}$     | $di_F/dt=100A/\mu s$ (Note 2)                       | -    | 2.6      | -         | $\mu C$  |

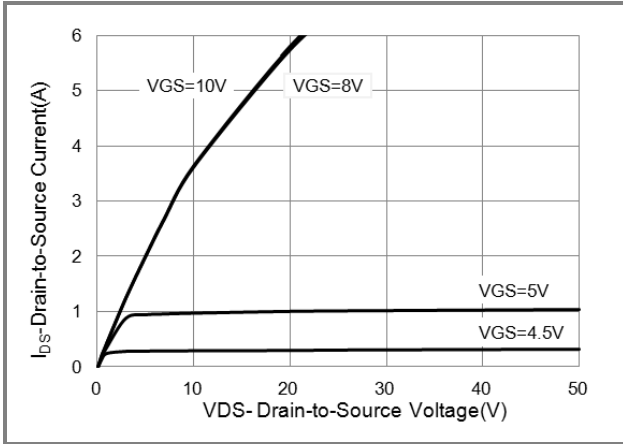
NOTES :

1.  $L=30\text{mH}, I_{AS}=4.7A, V_{DD}=50V, R_G=25\text{ohm},$  Starting  $T_J=25^\circ\text{C}$
2. Pulse width  $\leq 300\mu s,$  Duty cycle  $\leq 2\%$
3. Essentially independent of operating temperature typical characteristics.
4. Guaranteed by design, not subject to production testing

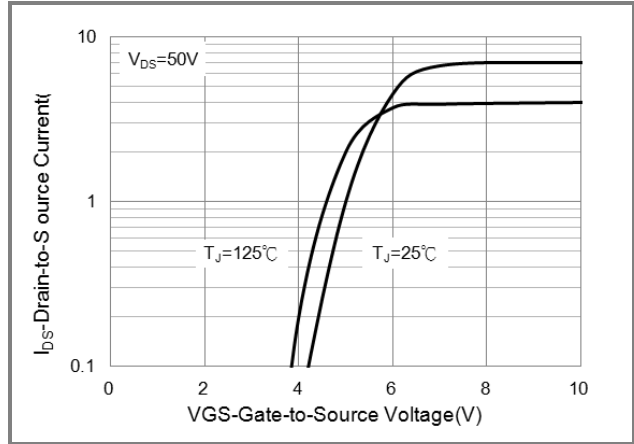


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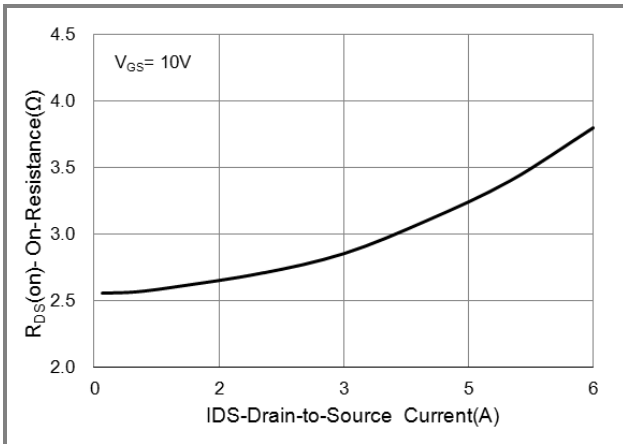
## TYPICAL CHARACTERISTIC CURVES



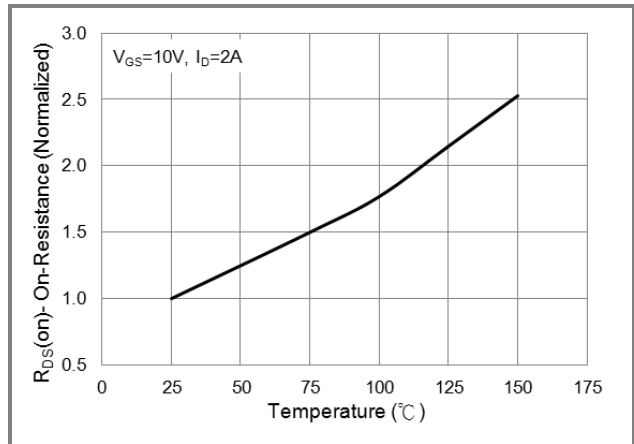
**Fig.1 Output Characteristics**



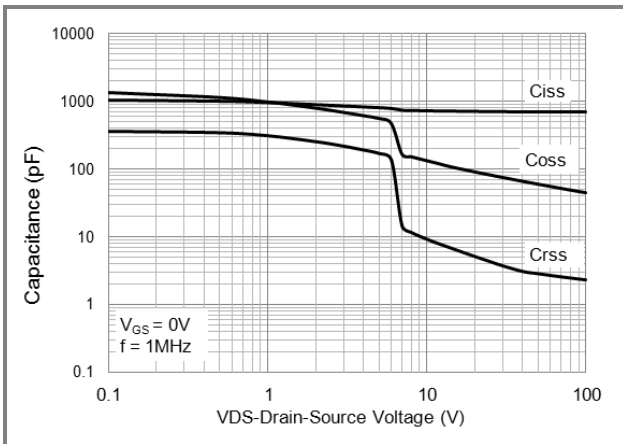
**Fig.2 Transfer Characteristics**



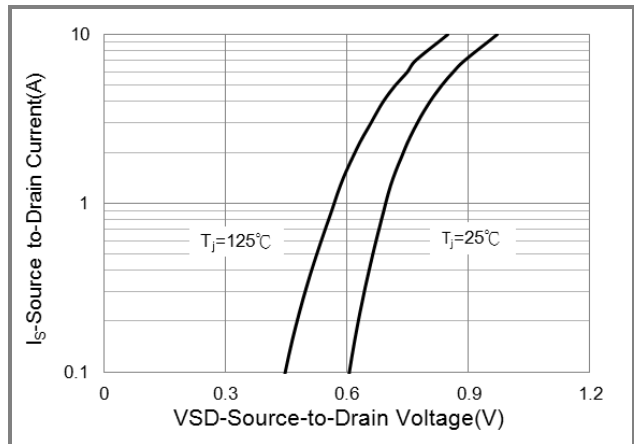
**Fig.3 On-Resistance vs. Drain Current**



**Fig.4 On-Resistance vs. Junction Temperature**



**Fig.5 Capacitance vs. Drain-Source Voltage**



**Fig.6 Source-Drain Diode Forward Voltage**



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## TYPICAL CHARACTERISTIC CURVES

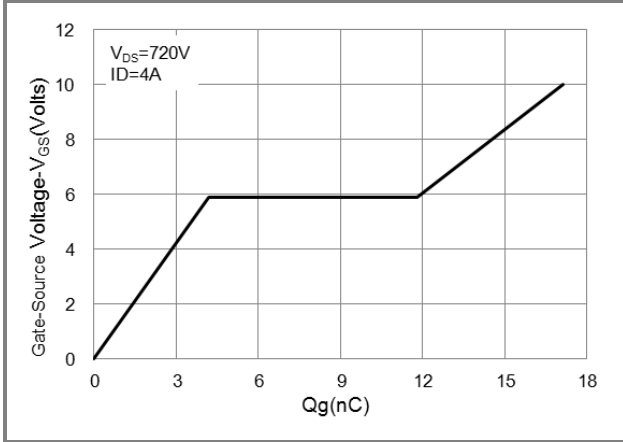


Fig.7 Gate Charge

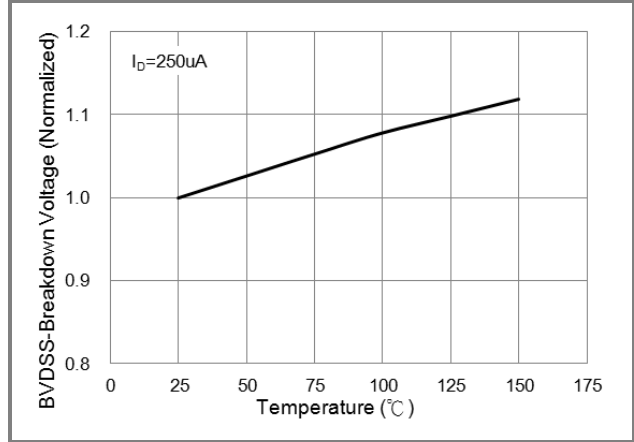


Fig.8 BV<sub>DSS</sub> vs. Junction Temperature

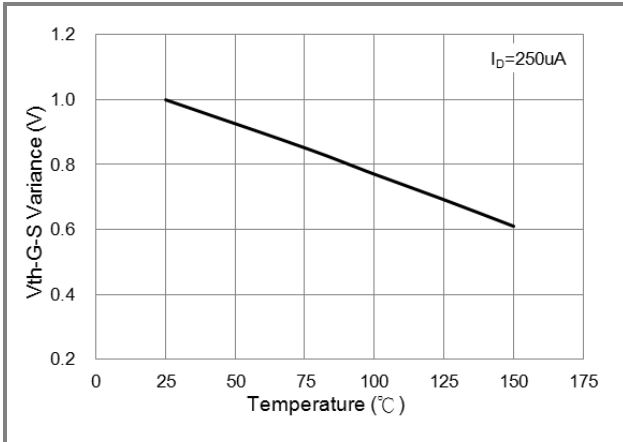


Fig.9 Threshold Voltage Variation with Temperature

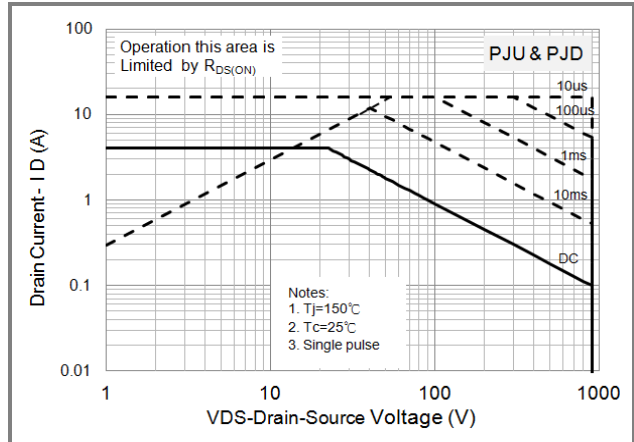


Fig.10 Maximum Safe Operating Area

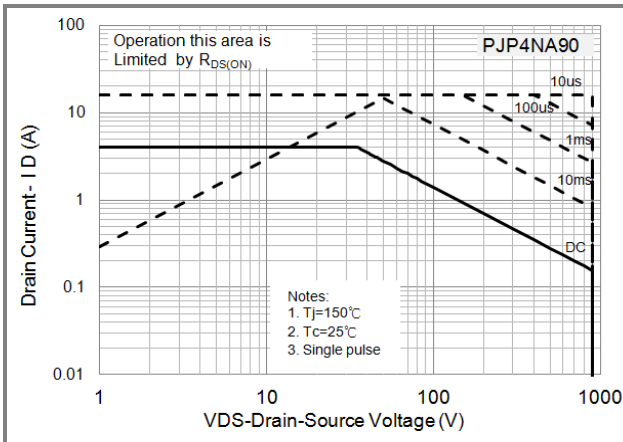


Fig.11 Maximum Safe Operating Area

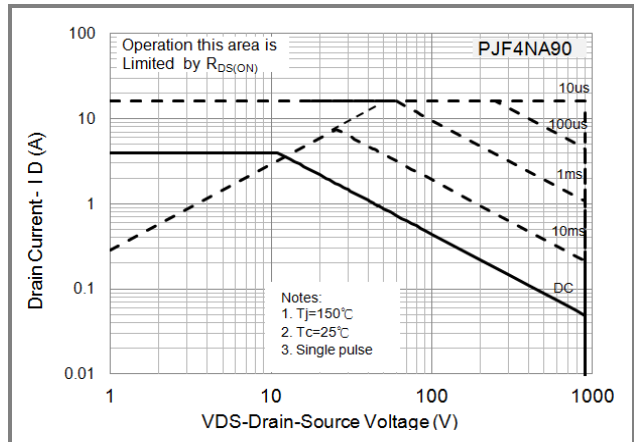


Fig.12 Maximum Safe Operating Area



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## TYPICAL CHARACTERISTIC CURVES

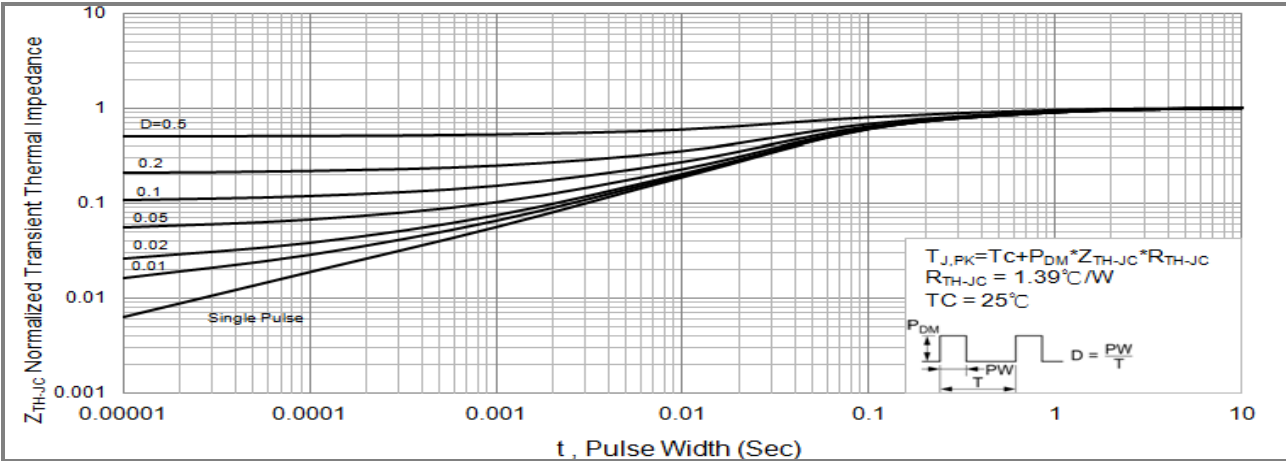


Fig.13 PJU/PJD Normalized Transient Thermal Impedance vs. Pulse Width

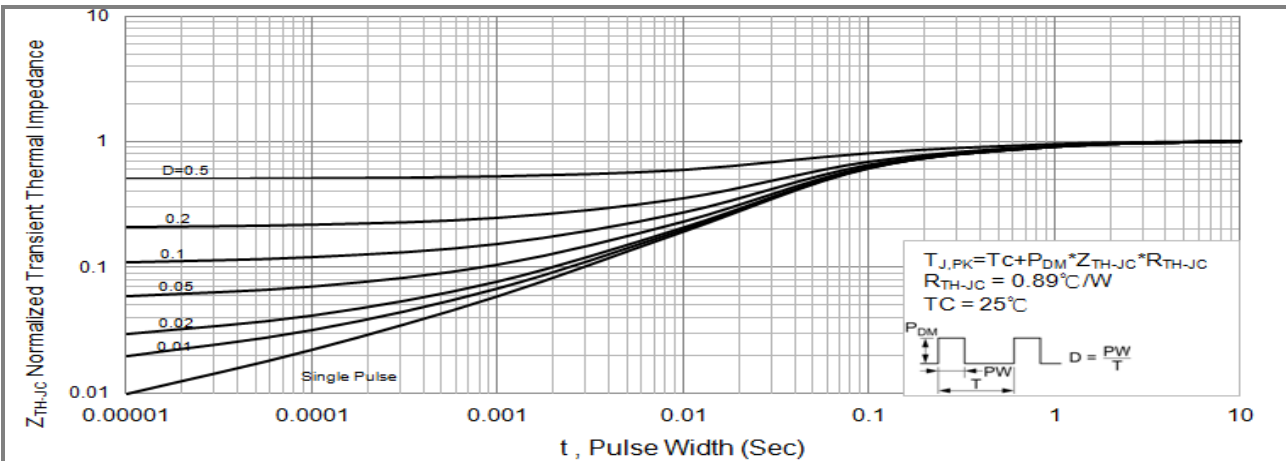


Fig.14 PJP4NA90 Normalized Transient Thermal Impedance vs. Pulse Width

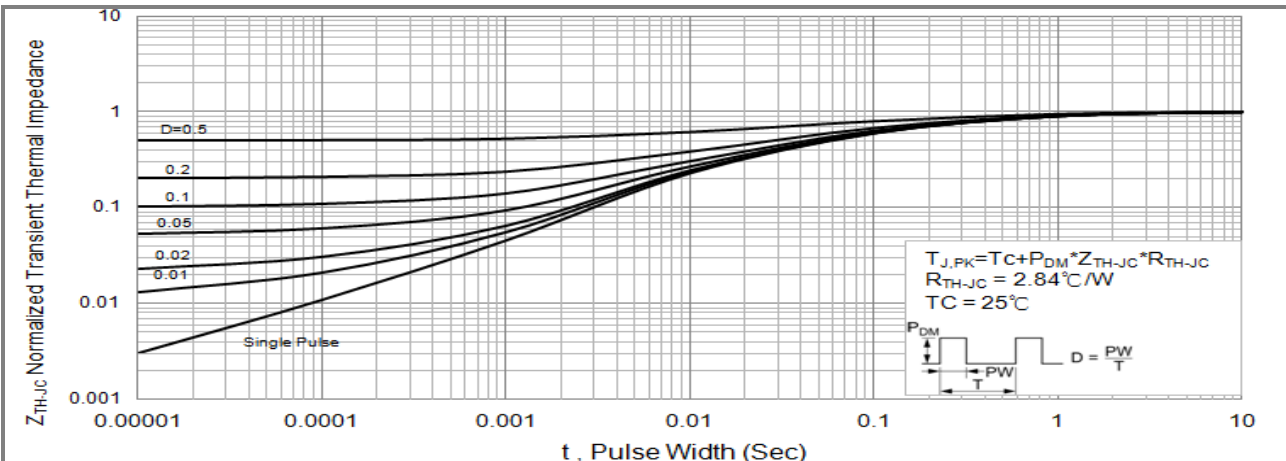
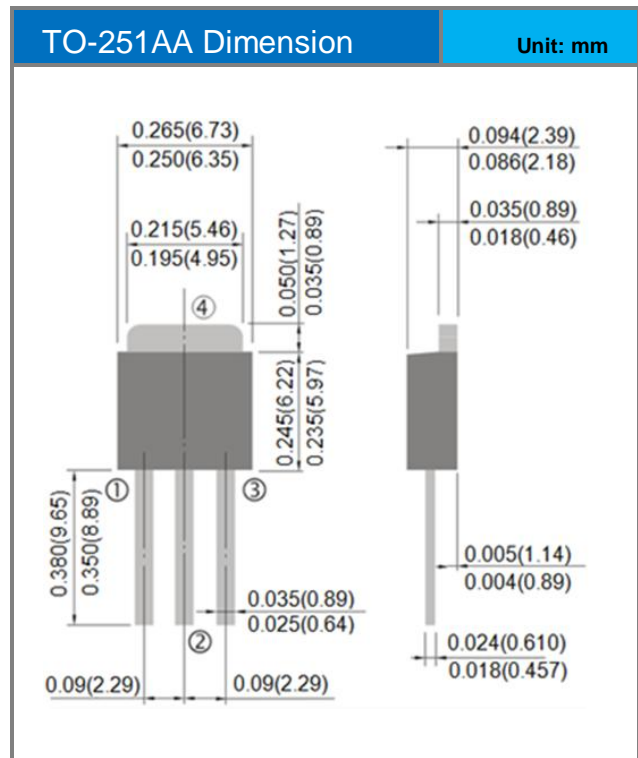
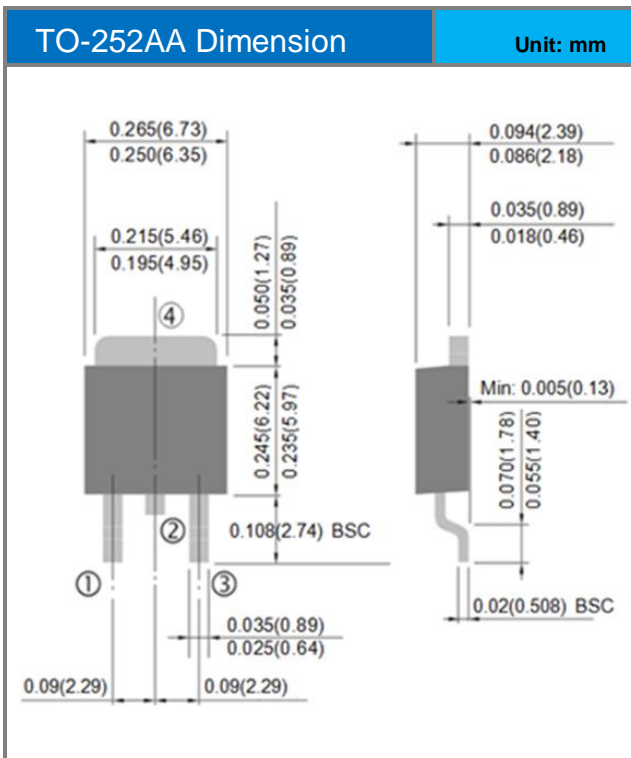
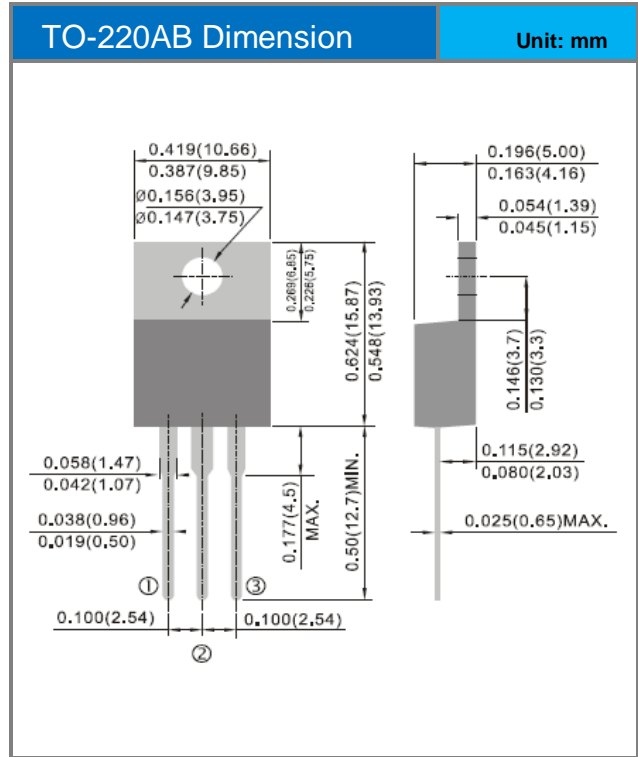
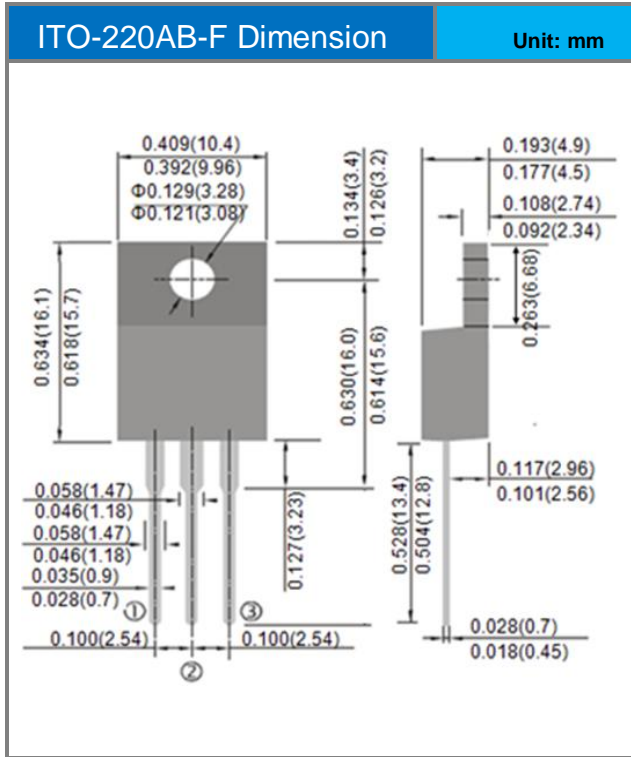


Fig.15 PJF4NA90 Normalized Transient Thermal Impedance vs. Pulse Width



# PJU4NA90 / PJD4NA90 / PJP4NA90 / PJF4NA90

## Packaging Information





## PJU4NA90 / PJD4NA90 / PJP4NA90 / PJF4NA90

### PART NO PACKING CODE VERSION

| Part No Packing Code | Package Type | Packing type        | Marking | Version      |
|----------------------|--------------|---------------------|---------|--------------|
| PJU4NA90_T0_00001    | TO-251AA     | 80pcs / Tube        | U4NA90  | Halogen free |
| PJD4NA90_L2_00001    | TO-252AA     | 3,000pcs / 13" reel | D4NA90  | Halogen free |
| PJP4NA90_T0_00001    | TO-220AB     | 50pcs / Tube        | P4NA90  | Halogen free |
| PJF4NA90_T0_00001    | ITO-220AB-F  | 50pcs / Tube        | F4NA90  | Halogen free |



## **PJU4NA90 / PJD4NA90 / PJP4NA90 / PJF4NA90**

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